

## MAX44264

## nanoPower Op Amp in a Tiny 6-Bump WLP

### General Description

The MAX44264 is an ultra-small (6-bump WLP) op amp that draws only 750nA of supply current. It operates from a single +1.8V to +5.5V supply and features ground-sensing inputs and rail-to-rail output. The ultralow supply current, low-operating voltage, and rail-to-rail output capabilities make these operational amplifiers ideal for use in single lithium ion (Li+), or two-cell NiCd or alkaline battery systems. The rail-to-rail output stage of the MAX44264 is capable of driving the output voltage to within 4mV of the rail with a 100k $\Omega$  load, and can sink and source 11mA with a +5V supply. The IC is unity-gain stable and available in a space-saving 0.9mm x 1.3mm, 6-bump WLP package.

### Applications

- Cell Phones
- Tablet/Notebook Computers
- Mobile Accessories
- Battery-Powered Devices

### Benefits and Features

- Ultra-Low 750nA Supply Current per Amplifier
- Ultra-Low +1.8V Supply Voltage Operation
- Ground-Sensing Input Common-Mode Range
- Outputs Swing Rail-to-Rail
- Outputs Source and Sink 11mA of Load Current
- No Phase Reversal for Overdriven Inputs
- High 120dB Open-Loop Voltage Gain
- Low 500 $\mu$ V Input Offset Voltage
- 9kHz Gain-Bandwidth Product
- 250pF (min) Capacitive Load Capability
- Available in a Tiny, 0.9mm x 1.3mm, 6-Bump WLP Package

### Ordering Information

| PART         | TEMP RANGE     | PIN-PACKAGE | TOP MARK |
|--------------|----------------|-------------|----------|
| MAX44264EWT+ | -40°C to +85°C | 6 WLP       | +CB      |

+Denotes a lead(Pb)-free/RoHS-compliant package.

## Absolute Maximum Ratings

$V_{DD}$  to  $V_{SS}$ .....-0.3V to +6V  
 $IN_+$  or  $IN_-$ .....( $V_{SS} - 0.3V$ ) to ( $V_{DD} + 0.3V$ )  
 $OUT_-$  Shorted to  $V_{SS}$  or  $V_{DD}$ .....Continuous  
 Continuous Power Dissipation ( $T_A = +70^\circ C$ )  
     6-Bump WLP (derate 10.5mW/ $^\circ C$  above  $+70^\circ C$ ).....840mW

Operating Temperature Range..... $-40^\circ C$  to  $+85^\circ C$   
 Junction Temperature..... $+150^\circ C$   
 Storage Temperature Range..... $-65^\circ C$  to  $+150^\circ C$   
 Lead Temperature (soldering, 10s)..... $+300^\circ C$   
 Soldering Temperature (reflow)..... $+260^\circ C$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## Electrical Characteristics

( $V_{DD} = +5V$ ,  $V_{SS} = 0V$ ,  $V_{CM} = 0V$ ,  $V_{OUT} = V_{DD}/2$ ,  $R_L = \infty$  to  $V_{DD}/2$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

| PARAMETER                       | SYMBOL    | CONDITIONS                                                 | MIN                | TYP        | MAX            | UNITS   |
|---------------------------------|-----------|------------------------------------------------------------|--------------------|------------|----------------|---------|
| Supply Voltage Range            | $V_{DD}$  | Guaranteed by PSRR tests                                   | 1.8                |            | 5.5            | V       |
| Supply Current (per Amplifier)  | $I_{DD}$  | $V_{DD} = +1.8V$                                           |                    | 0.6        |                | $\mu A$ |
|                                 |           | $V_{DD} = +5.0V$                                           |                    | 0.75       | 1.2            |         |
| Input Offset Voltage            | $V_{OS}$  |                                                            |                    | $\pm 0.5$  | $\pm 7.0$      | mV      |
| Input Bias Current              | $I_B$     |                                                            |                    | $\pm 200$  | $\pm 1500$     | pA      |
| Input Offset Current            | $I_{OS}$  |                                                            |                    | $\pm 12.5$ |                | pA      |
| Input Common-Mode Voltage Range | $V_{CM}$  | Guaranteed by the CMRR test                                | $V_{SS}$           |            | $V_{DD} - 1.1$ | V       |
| Common-Mode Rejection Ratio     | CMRR      | Specified with $V_{SS} \leq V_{CM} \leq (V_{DD} - 1.1V)$   | 70                 | 95         |                | dB      |
| Power-Supply Rejection Ratio    | PSRR      | $+1.8V \leq V_{DD} \leq +5.5V$                             | 70                 | 90         |                | dB      |
| Large-Signal Voltage Gain       | $A_{VOL}$ | $R_L = 1M\Omega$ , $V_{OUT} = 50mV$ to $V_{DD} - 50mV$     | 90                 | 120        |                | dB      |
|                                 |           | $R_L = 100k\Omega$ , $V_{OUT} = 200mV$ to $V_{DD} - 200mV$ | 90                 | 112        |                |         |
|                                 |           | $R_L = 10k\Omega$ , $V_{OUT} = 200mV$ to $V_{DD} - 200mV$  |                    | 100        |                |         |
| Output Voltage Swing            | $V_{OH}$  | Swing high specified as $V_{DD} - V_{OH}$                  | $R_L = 1M\Omega$   | 1          | 4              | mV      |
|                                 |           |                                                            | $R_L = 100k\Omega$ | 4          | 10             |         |
|                                 |           |                                                            | $R_L = 10k\Omega$  | 40         |                |         |
|                                 | $V_{OL}$  | Swing low specified as $V_{OL} - V_{SS}$                   | $R_L = 1M\Omega$   | 0.5        | 5              |         |
|                                 |           |                                                            | $R_L = 100k\Omega$ | 1          | 5              |         |
|                                 |           |                                                            | $R_L = 10k\Omega$  | 10         |                |         |
| Gain-Bandwidth Product          | GBW       |                                                            |                    | 9          |                | kHz     |
| Phase Margin                    | $\Phi_M$  |                                                            |                    | 90         |                | degrees |

**Electrical Characteristics (continued)**(V<sub>DD</sub> = +5V, V<sub>SS</sub> = 0V, V<sub>CM</sub> = 0V, V<sub>OUT</sub> = V<sub>DD</sub>/2, R<sub>L</sub> = ∞ to V<sub>DD</sub>/2, T<sub>A</sub> = +25°C, unless otherwise noted.)

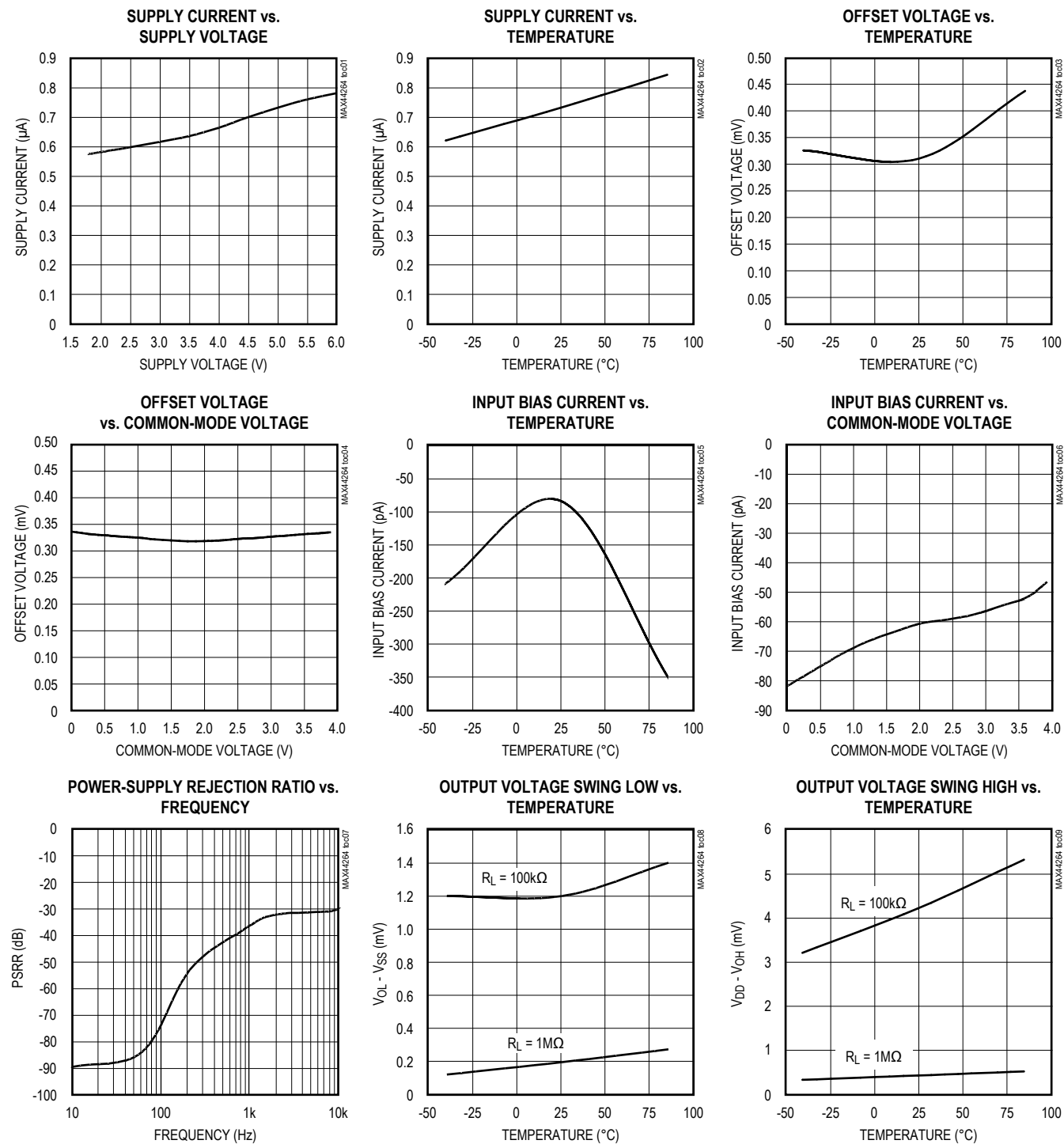
| PARAMETER                    | SYMBOL            | CONDITIONS                            | MIN | TYP | MAX | UNITS  |
|------------------------------|-------------------|---------------------------------------|-----|-----|-----|--------|
| Slew Rate                    | SR                | V <sub>OUT</sub> = 4V step            |     | 2   |     | V/ms   |
| Input Voltage Noise          | e <sub>n</sub>    | f = 1kHz                              |     | 150 |     | nV/√Hz |
|                              |                   | f = 10kHz                             |     | 120 |     |        |
| Output Short-Circuit Current |                   | Shorted to V <sub>SS</sub> (sourcing) |     | 11  |     | mA     |
|                              |                   | Shorted to V <sub>DD</sub> (sinking)  |     | 36  |     |        |
| Power-On Time                | t <sub>ON</sub>   |                                       |     | 2   |     | μs     |
| Power-Off Time               | t <sub>OFF</sub>  |                                       |     | 2   |     | μs     |
| Capacitive Load              | C <sub>LOAD</sub> | No sustained oscillations             | 250 |     |     | pF     |

**Electrical Characteristics**(V<sub>DD</sub> = +5V, V<sub>SS</sub> = 0V, V<sub>CM</sub> = 0V, V<sub>OUT</sub> = V<sub>DD</sub>/2, R<sub>L</sub> = ∞ to V<sub>DD</sub>/2, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted.) (Note 1)

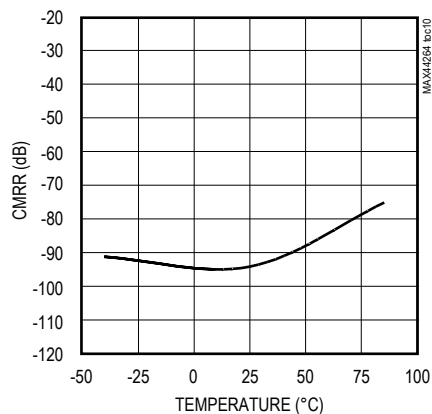
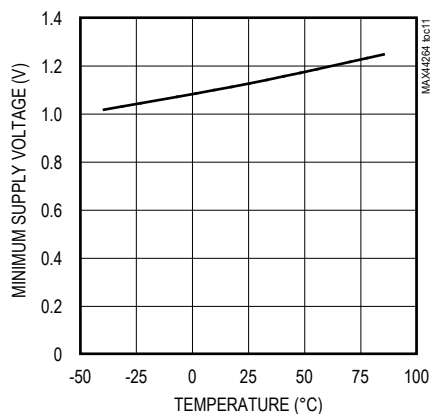
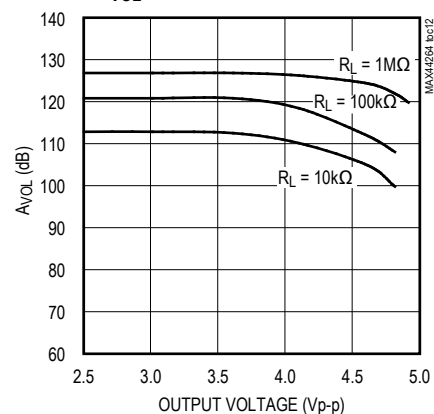
| PARAMETER                                    | SYMBOL            | CONDITIONS                                                                  | MIN                    | TYP | MAX                   | UNITS |
|----------------------------------------------|-------------------|-----------------------------------------------------------------------------|------------------------|-----|-----------------------|-------|
| Supply Voltage Range                         | V <sub>DD</sub>   | Guaranteed by PSRR tests                                                    | 1.8                    |     | 5.5                   | V     |
| Supply Current (per Amplifier)               | I <sub>DD</sub>   | V <sub>DD</sub> = +5.0V                                                     |                        |     | 1.5                   | μA    |
| Input Offset Voltage                         | V <sub>OS</sub>   |                                                                             |                        |     | ±15                   | mV    |
| Input Offset Voltage Temperature Coefficient | TCV <sub>OS</sub> |                                                                             |                        | 8   |                       | μV/°C |
| Input Bias Current                           | I <sub>B</sub>    |                                                                             |                        |     | 4.25                  | nA    |
| Input Common-Mode Voltage Range              | V <sub>CM</sub>   | Guaranteed by the CMRR test                                                 | V <sub>SS</sub>        |     | V <sub>DD</sub> - 1.1 | V     |
| Common-Mode Rejection Ratio                  | CMRR              | V <sub>SS</sub> ≤ V <sub>CM</sub> ≤ (V <sub>DD</sub> - 1.1V)                | 56                     |     |                       | dB    |
| Power-Supply Rejection Ratio                 | PSRR              | +1.8V ≤ V <sub>DD</sub> ≤ +5.5V, 0°C ≤ T <sub>A</sub> ≤ +85°C               | 65                     |     |                       | dB    |
|                                              |                   | +2V ≤ V <sub>DD</sub> ≤ +5.5V, -40°C ≤ T <sub>A</sub> ≤ +85°C               | 65                     |     |                       |       |
| Large-Signal Voltage Gain                    | A <sub>VOL</sub>  | V <sub>OUT</sub> = 50mV to V <sub>DD</sub> - 50mV, R <sub>L</sub> = 1MΩ     | 75                     |     |                       | dB    |
|                                              |                   | V <sub>OUT</sub> = 200mV to V <sub>DD</sub> - 200mV, R <sub>L</sub> = 100kΩ | 75                     |     |                       |       |
| Output Voltage Swing                         | V <sub>OH</sub>   | Swing high specified as V <sub>DD</sub> - V <sub>OH</sub>                   | R <sub>L</sub> = 1MΩ   |     | 5                     | mV    |
|                                              |                   |                                                                             | R <sub>L</sub> = 100kΩ |     | 15                    |       |
|                                              | V <sub>OL</sub>   | Swing low specified as V <sub>OL</sub> - V <sub>SS</sub>                    | R <sub>L</sub> = 1MΩ   |     | 5                     |       |
|                                              |                   |                                                                             | R <sub>L</sub> = 100kΩ |     | 5                     |       |

**Note 1:** All devices are production tested at T<sub>A</sub> = +25°C. All temperature limits are guaranteed by design.

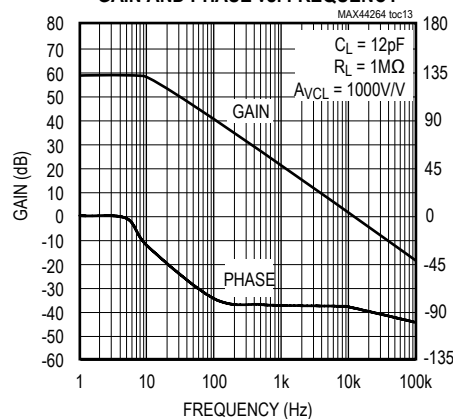
## Typical Operating Characteristics

(V<sub>DD</sub> = +5V, V<sub>SS</sub> = 0V, V<sub>CM</sub> = 0V, R<sub>L</sub> = 100kΩ to V<sub>DD</sub>/2, T<sub>A</sub> = +25°C, unless otherwise noted.)

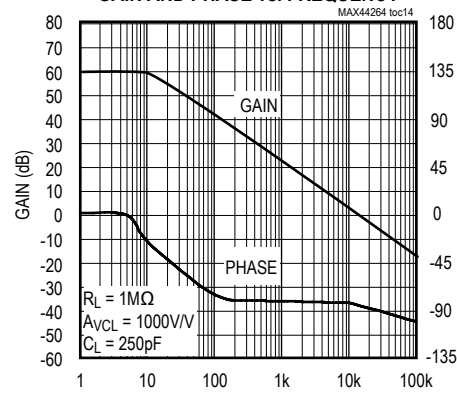
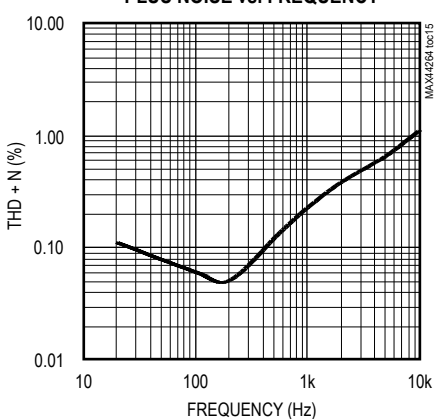
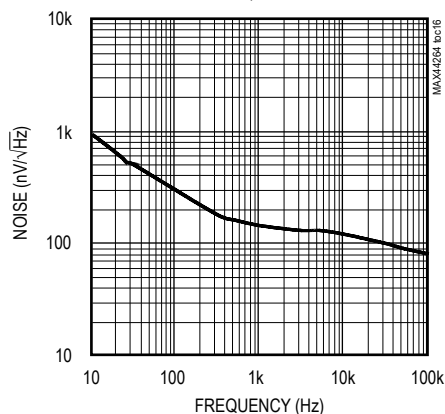
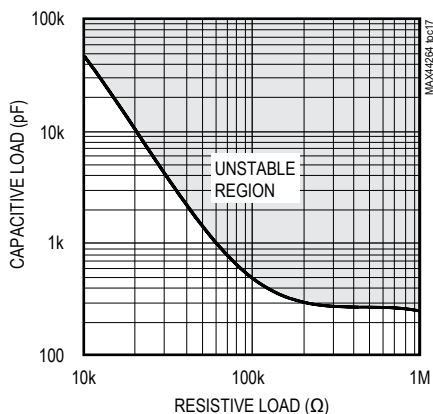
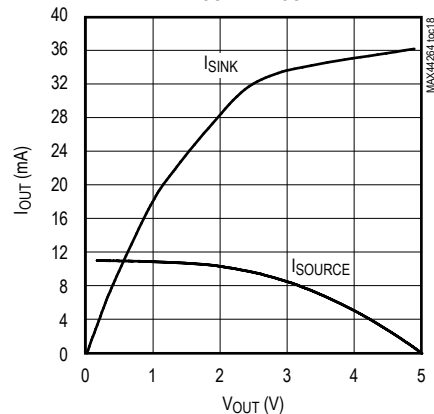
## Typical Operating Characteristics (continued)

(V<sub>DD</sub> = +5V, V<sub>SS</sub> = 0V, V<sub>CM</sub> = 0V, R<sub>L</sub> = 100kΩ to V<sub>DD</sub>/2, T<sub>A</sub> = +25°C, unless otherwise noted.)COMMON-MODE REJECTION RATIO vs.  
TEMPERATUREMINIMUM SUPPLY VOLTAGE  
vs. TEMPERATUREA<sub>voL</sub> vs. OUTPUT VOLTAGE SWING

GAIN AND PHASE vs. FREQUENCY



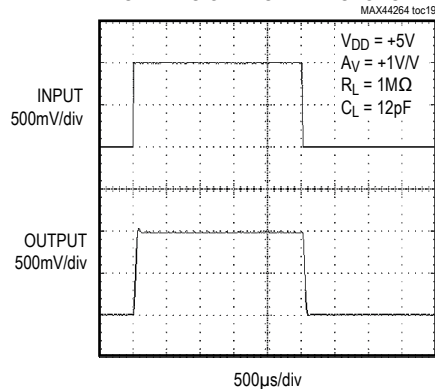
GAIN AND PHASE vs. FREQUENCY

TOTAL HARMONIC DISTORTION  
PLUS NOISE vs. FREQUENCYVOLTAGE NOISE DENSITY vs.  
FREQUENCYSTABILITY vs. CAPACITIVE  
AND RESISTIVE LOADSI<sub>OUT</sub> vs. V<sub>OUT</sub>

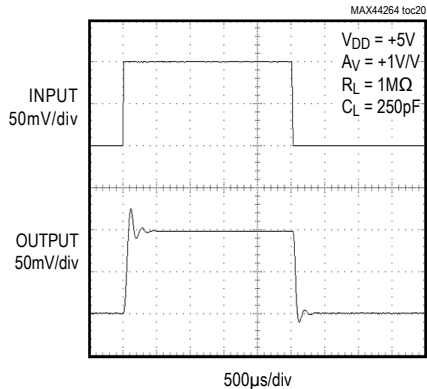
## Typical Operating Characteristics (continued)

(V<sub>DD</sub> = +5V, V<sub>SS</sub> = 0V, V<sub>CM</sub> = 0V, R<sub>L</sub> = 100kΩ to V<sub>DD</sub>/2, T<sub>A</sub> = +25°C, unless otherwise noted.)

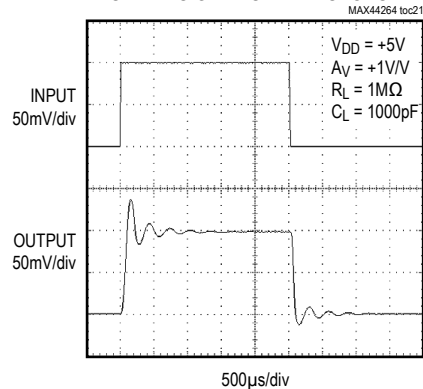
SMALL-SIGNAL STEP RESPONSE



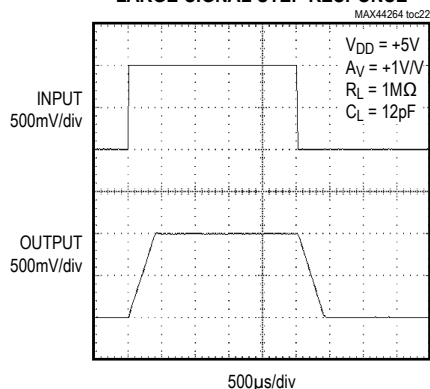
SMALL-SIGNAL STEP RESPONSE



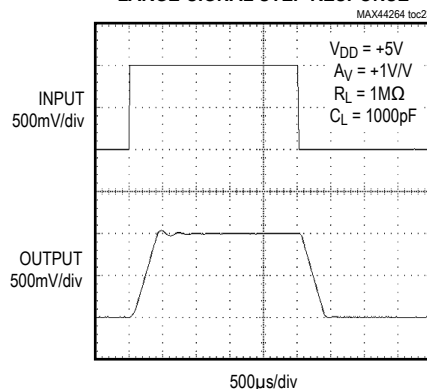
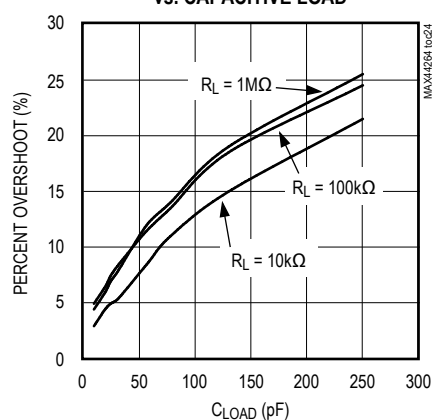
SMALL-SIGNAL STEP RESPONSE



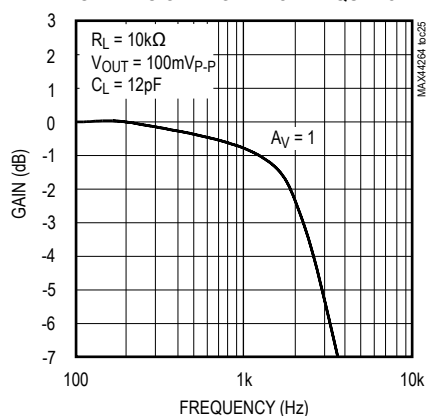
LARGE-SIGNAL STEP RESPONSE



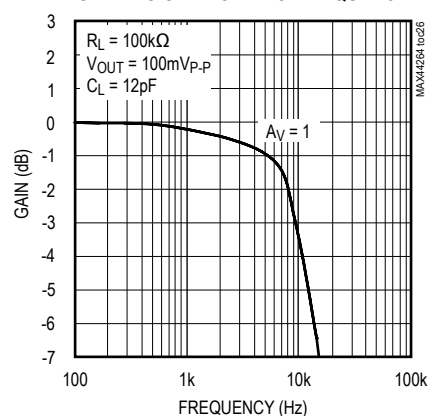
LARGE-SIGNAL STEP RESPONSE

PERCENT OVERSHOOT  
vs. CAPACITIVE LOAD

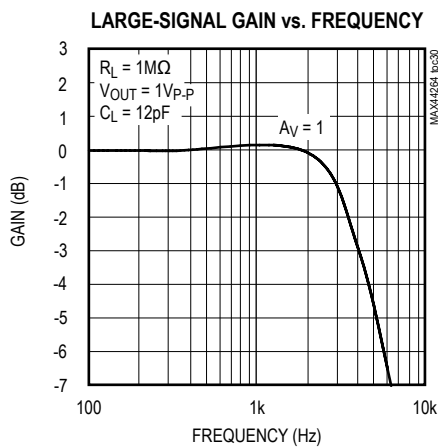
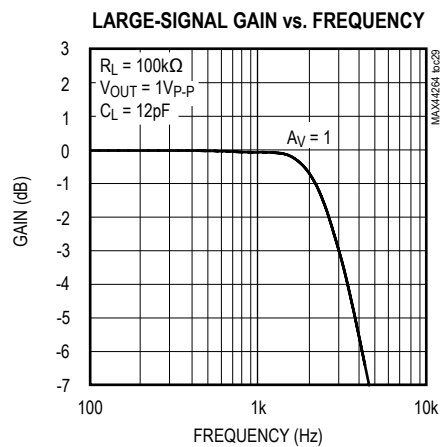
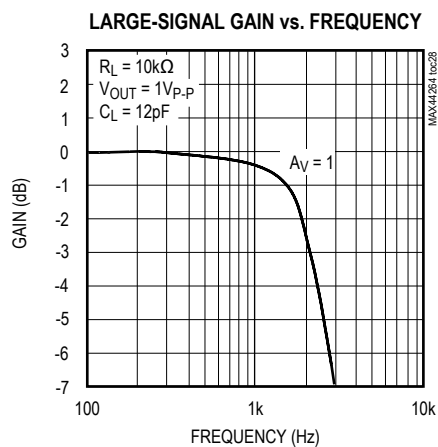
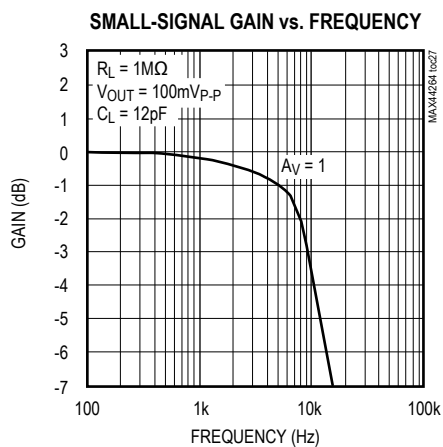
SMALL-SIGNAL GAIN vs. FREQUENCY



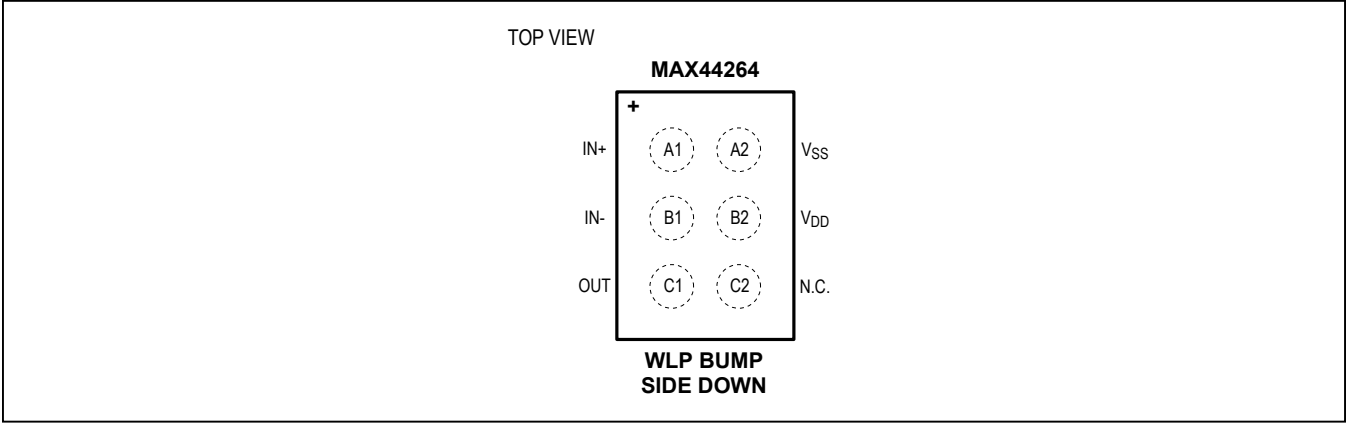
SMALL-SIGNAL GAIN vs. FREQUENCY



## Typical Operating Characteristics (continued)

(V<sub>DD</sub> = +5V, V<sub>SS</sub> = 0V, V<sub>CM</sub> = 0V, R<sub>L</sub> = 100kΩ to V<sub>DD</sub>/2, T<sub>A</sub> = +25°C, unless otherwise noted.)

Pin Configuration



Pin Description

| PIN | NAME            | FUNCTION                                 |
|-----|-----------------|------------------------------------------|
| A1  | IN+             | Noninverting Amplifier Input             |
| A2  | V <sub>SS</sub> | Negative Power-Supply Voltage            |
| B1  | IN-             | Inverting Amplifier Input                |
| B2  | V <sub>DD</sub> | Positive Power-Supply Voltage            |
| C1  | OUT             | Amplifier Output                         |
| C2  | N.C.            | No Connection. Not internally connected. |

Applications Information

Ground Sensing

The common-mode input range of the MAX44264 extends down to ground, and offers excellent common-mode rejection. These devices are guaranteed not to undergo phase reversal when the input is overdriven.

Power Supplies and Layout

The IC operates from a single +1.8V to +5.5V power supply. Bypass power supplies with a 0.1μF ceramic capacitor placed close to the V<sub>DD</sub> pin.

Ground layout improves performance by decreasing the amount of stray capacitance and noise at the op amp's inputs and outputs. To decrease stray capacitance, minimize PCB lengths and resistor leads, and place external components close to the op amps' pins.

Bandwidth

The IC is internally compensated for unity-gain stability and has a typical gain-bandwidth of 9kHz.

Stability

The IC maintains stability in their minimum gain configuration while driving capacitive loads. Although this product family is primarily designed for low-frequency applications,

good layout is extremely important because low-power requirements demand high-impedance circuits. The layout should also minimize stray capacitance at the amplifier inputs. However some stray capacitance may be unavoidable, and it may be necessary to add a 2pF to 10pF capacitor across the feedback resistor as shown in [Figure 1](#). Select the smallest capacitor value that ensures stability.

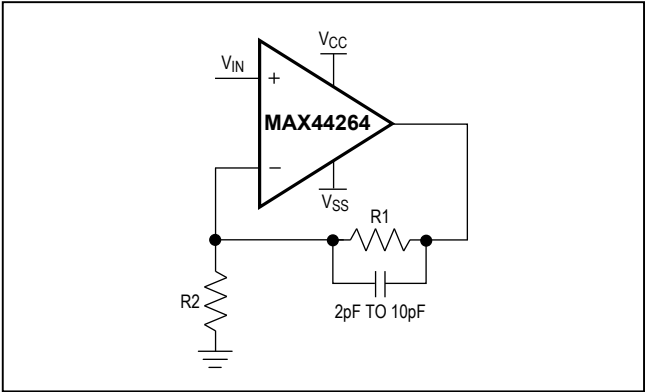


Figure 1. Compensation for Feedback Node Capacitance

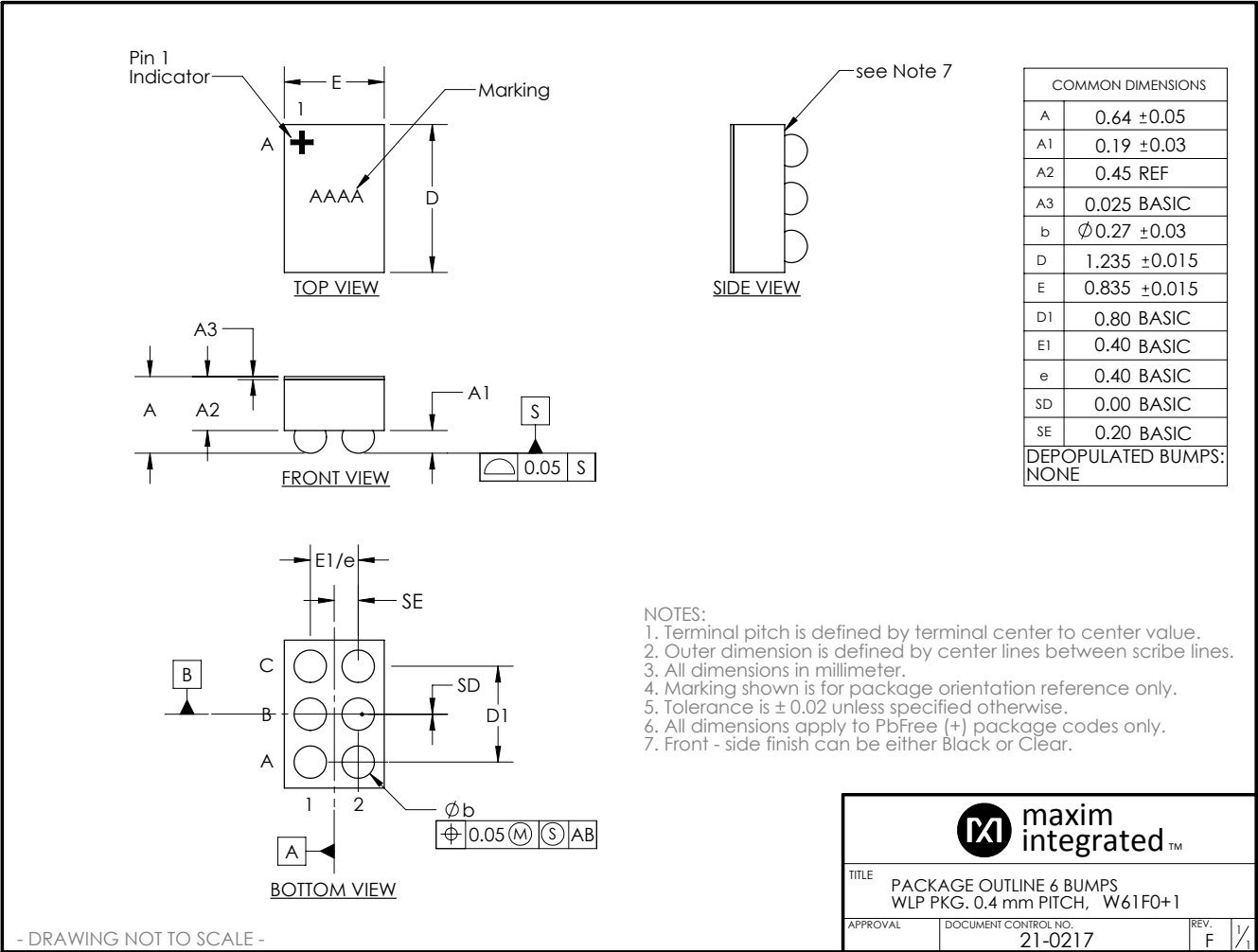
Chip Information  
PROCESS: BiCMOS



Package Information

For the latest package outline information and land patterns (footprints), go to [www.maximintegrated.com/packages](http://www.maximintegrated.com/packages). Note that a “+”, “#”, or “-” in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

| PACKAGE TYPE | PACKAGE CODE | OUTLINE NO.             | LAND PATTERN NO. |
|--------------|--------------|-------------------------|------------------|
| 6 WLP        | W61B1+1      | <a href="#">21-0217</a> | —                |



MAX44264

nanoPower Op Amp in  
a Tiny 6-Bump WLP

## Revision History

| REVISION<br>NUMBER | REVISION<br>DATE | DESCRIPTION                          | PAGES<br>CHANGED |
|--------------------|------------------|--------------------------------------|------------------|
| 0                  | 12/10            | Initial release                      | —                |
| 1                  | 3/17             | Updated title to include “nanoPower” | 1–10             |

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim Integrated's website at [www.maximintegrated.com](http://www.maximintegrated.com).

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